NSN 5961-01-329-9536



Diode Semiconductor Device - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-329-9536 **Inclosure Material:** Ceramic **Overall Length:** Between 0.096 inches and 0.104 inches **Terminal Length:** Between 0.125 inches and 0.175 inches **Overall Height:** Between 0.031 inches and 0.052 inches **Overall Width:** Between 0.096 inches and 0.104 inches **Function For Which Designed:** Limiter **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 15.0 breakdown voltage, dc **Power Rating Per Characteristic:** 2.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Precious Material And Location:** Terminal surfaces gold **Precious Material:** Gold **Terminal Type And Quantity:** 2 insulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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